



GEORG-AUGUST-UNIVERSITÄT
GÖTTINGEN



Pixel Radiation Damage Measurements with ATLAS

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on behalf of ATLAS Pixel Group

LHC Pixel Radiation Damage Workshop

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Bundesministerium
für Bildung
und Forschung

BMBF-Forschungsschwerpunkt
ATLAS-EXPERIMENT

FSP 103

Physik bei höchsten Energien mit dem ATLAS-Experiment am LHC

ATLAS

ATLAS Insertable B-Layer modules and front-ends (FE-I4)

Properties evolution with radiation fluence

Studies of property vs. time/luminosity/fluence

- Depletion voltage
 - Collision data (vs luminosity)
 - Beam test (before/after irradiation)
- Charge collection efficiency
- Lorentz angle

Depletion voltage vs. longitudinal position

Absorbed radiation fluence changes along the detector

- Cross-check against leakage-current behaviour

Depletion voltage measurement



Signal from FE such as:

Charge \sim Amplitude \sim ToT

with ToT = Time over Threshold

Measure Charge vs. Module Bias Voltage (V)

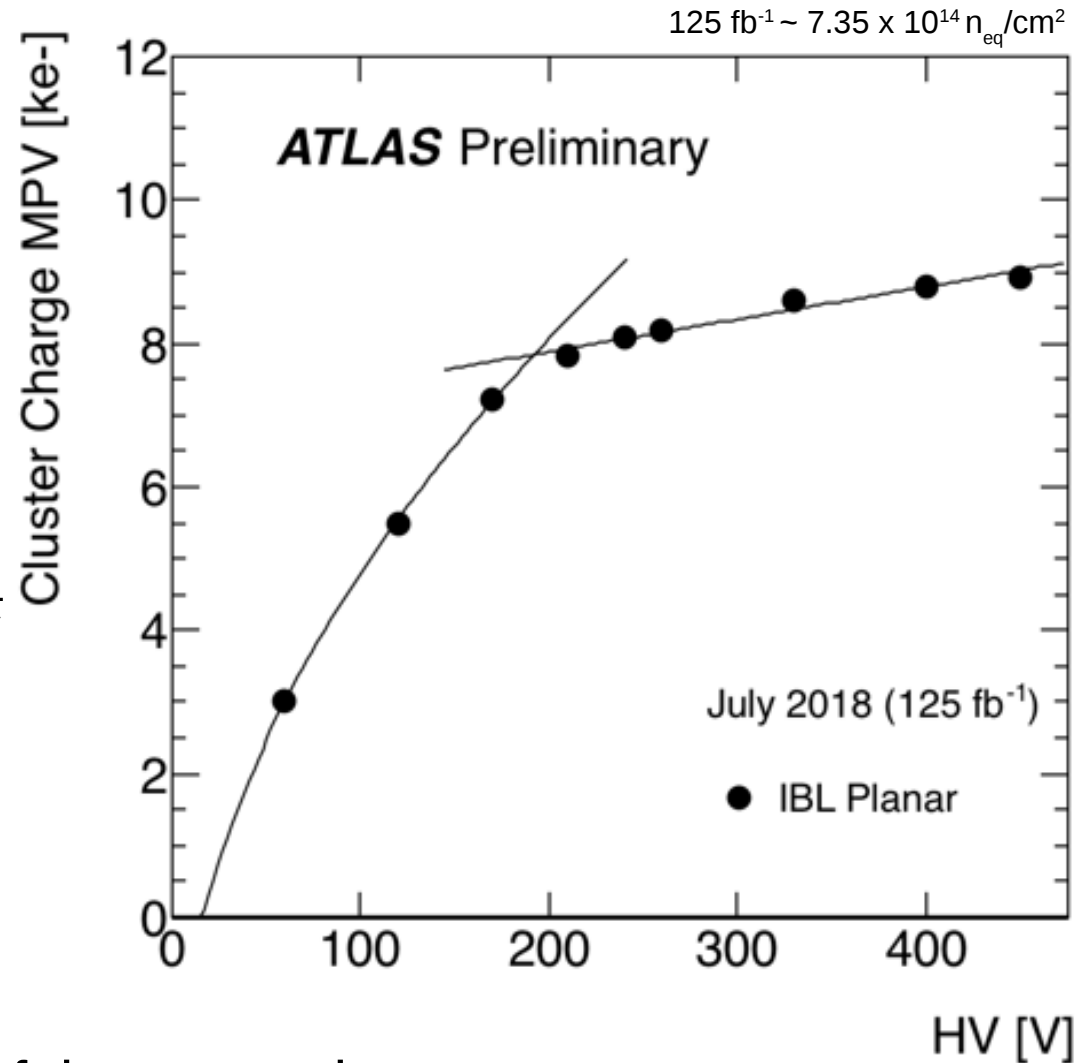
Underdepleted module:

Charge \sim Width_{depl} $\sim \sqrt{V}$

Over-depleted module:

Charge $\sim V$

Depletion voltage: interception of the two regimes



Collision data



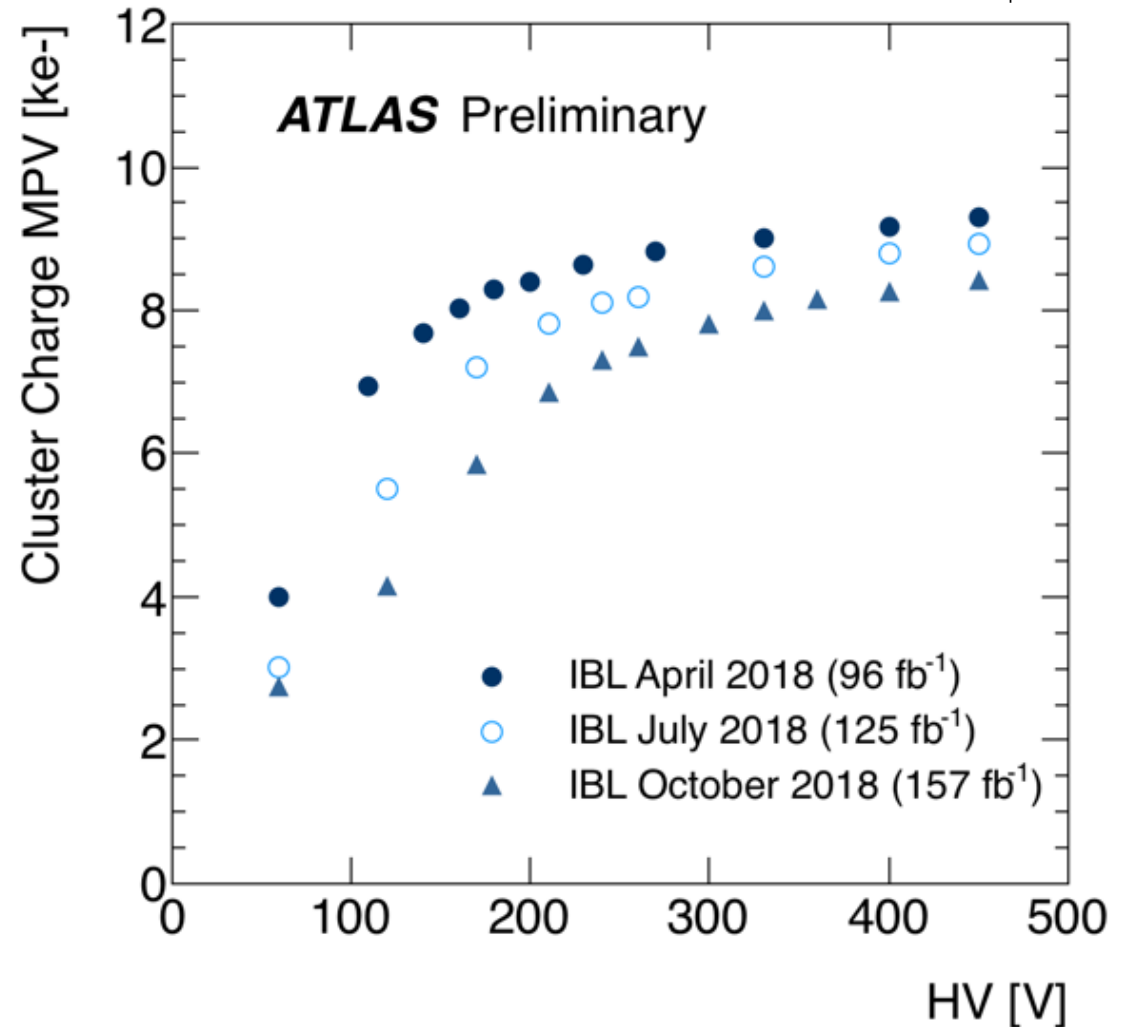
96 fb⁻¹ ~ 5.6 × 10¹⁴ n_{eq}/cm²
125 fb⁻¹ ~ 7.6 × 10¹⁴ n_{eq}/cm²
157 fb⁻¹ ~ 9.2 × 10¹⁴ n_{eq}/cm²

ATLAS performed dedicated voltage scans during data-taking

Track selection:

- $p_T > 1$ GeV
- No shared clusters
- Pixels multiplicity in clusters:
 - $N_x < 4$ – pitch = 50 μm
 - $N_y = 1$ – pitch = 200 μm

Charge (ToT) distribution corrected by $\cos(\text{inc. angle})$
→ Landau distribution on Minimum Ionisation Point (MIP)



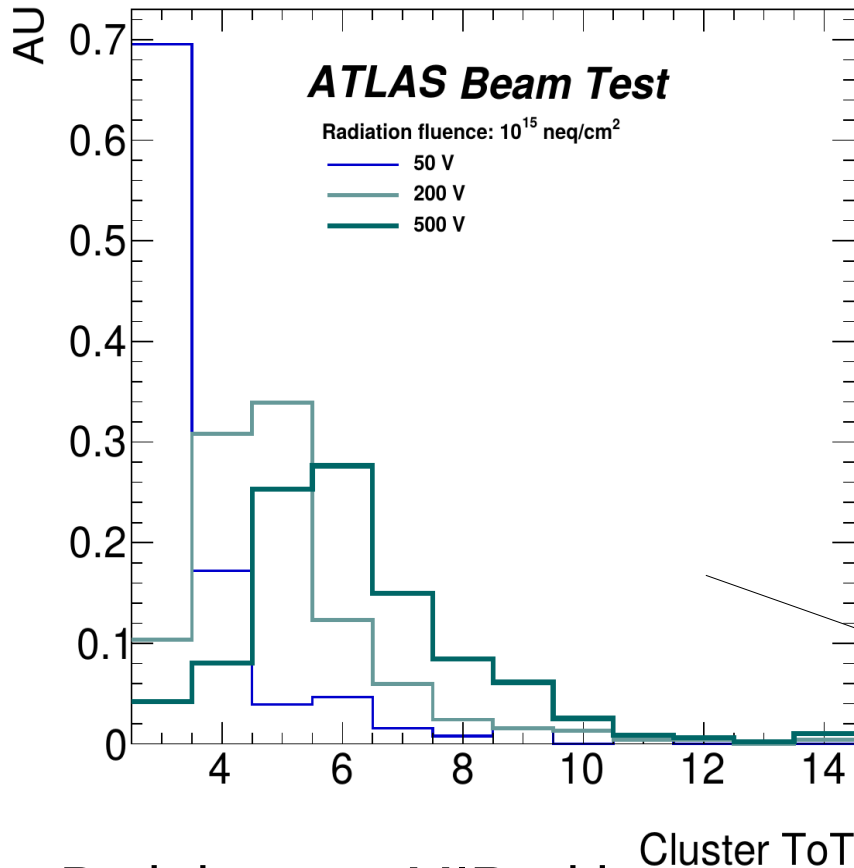
Fit of charge distribution → Most Probable Value (MPV) vs bias voltage

Beam test



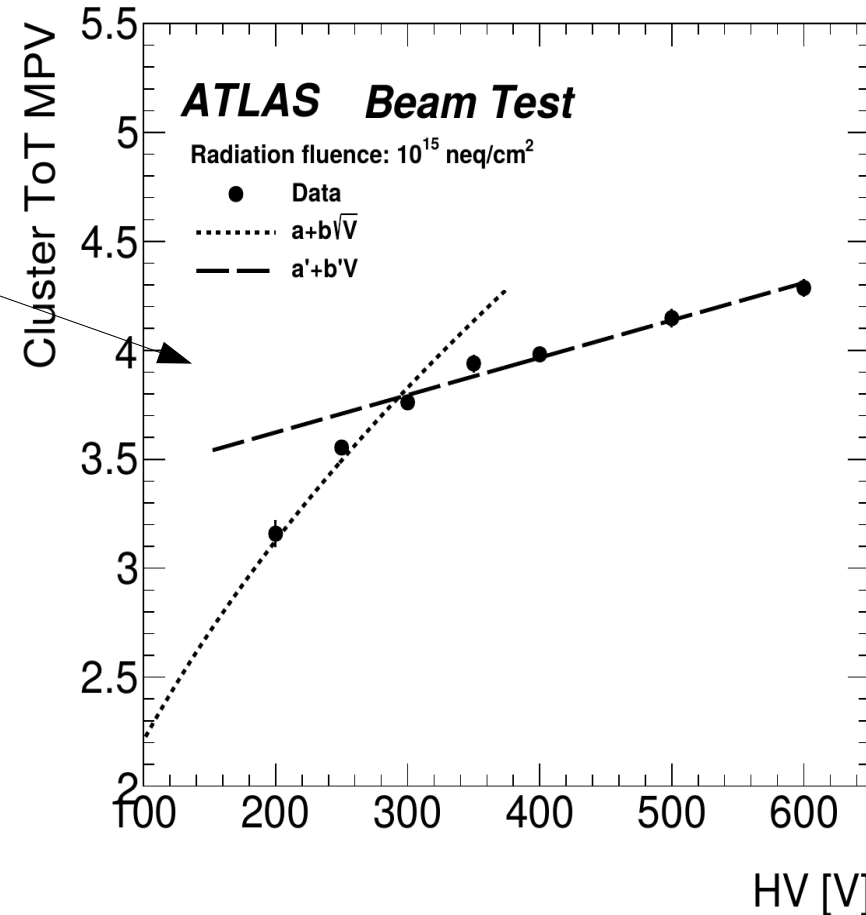
Same IBL module (D31-18-01) tested in two different beam tests:

- Fluence = $0 \text{ n}_{\text{eq}}/\text{cm}^2$
Fermilab, March 2018
- Fluence = $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
CERN H8, September 2018



Both beams: MIP with perpendicular incidence

Fit of ToT distribution (\sim charge)
→ MPV vs. Bias voltage



n_{eq} = Silicon 1 MeV neutron equivalent dose

Results on depletion voltage

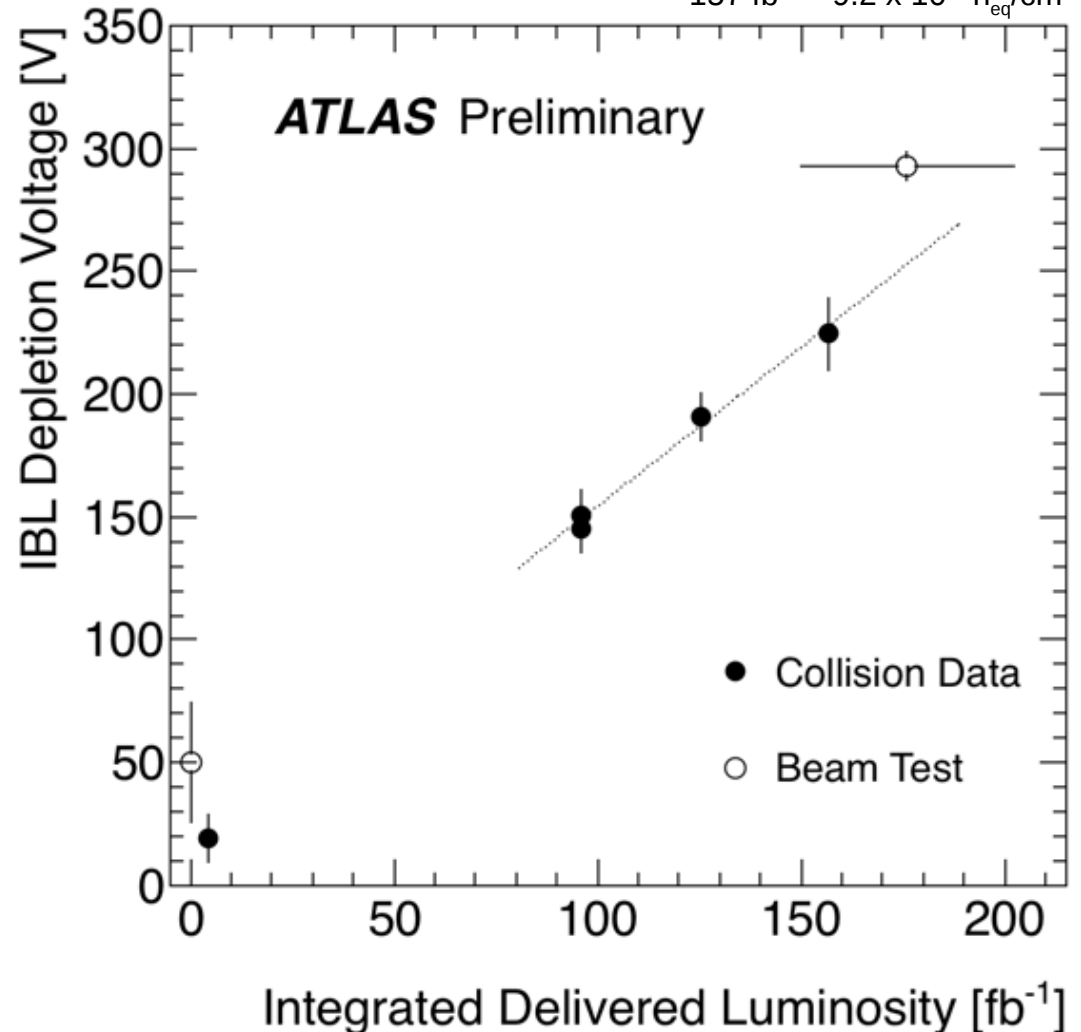


Measured depletion voltage as function of luminosity.

End Run II fluence $\sim 10^{15} n_{eq}/cm^2$

Similar results observed in beam test and collision data (2015 + 2018)

93 fb⁻¹ $\sim 5.4 \times 10^{14} n_{eq}/cm^2$
96 fb⁻¹ $\sim 5.6 \times 10^{14} n_{eq}/cm^2$
125 fb⁻¹ $\sim 7.6 \times 10^{14} n_{eq}/cm^2$
157 fb⁻¹ $\sim 9.2 \times 10^{14} n_{eq}/cm^2$



	Slope [V / fb ⁻¹]
Collision Data 2018	1.39 ± 0.10

Charge collection efficiency

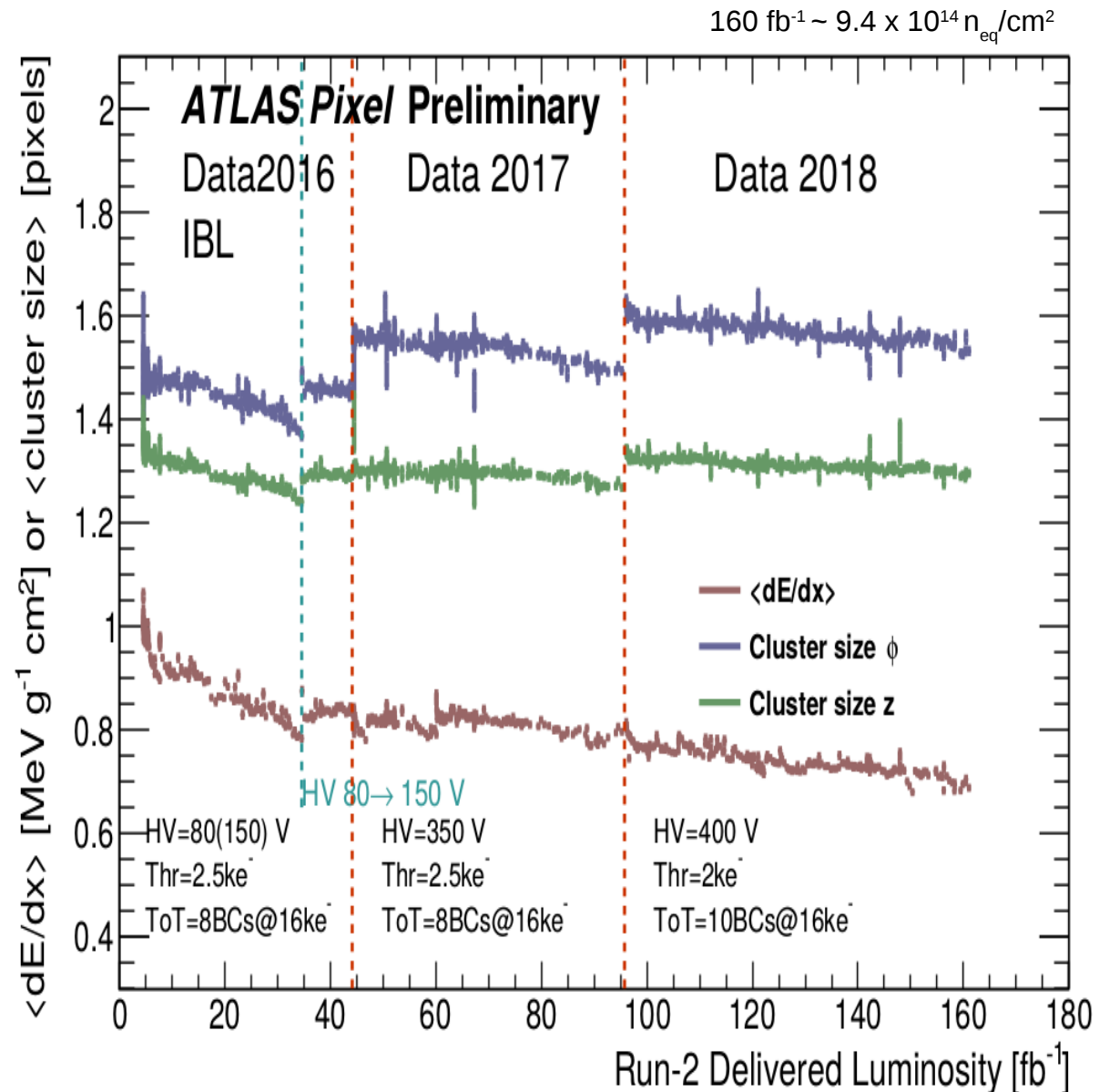


Studied as function of luminosity:

- Fit of charge distribution (corrected by incidence angle)
- Normalised for the sensor thickness (dE/dx)

Clear trend in luminosity, that is absorbed fluence.

Trend also in cluster shapes indicating a loss of collected charge.



Lorentz angle



Ionisation charge drift azimuthal angle due to external magnetic field and bias electric field

Sensor bulk defects change electric field

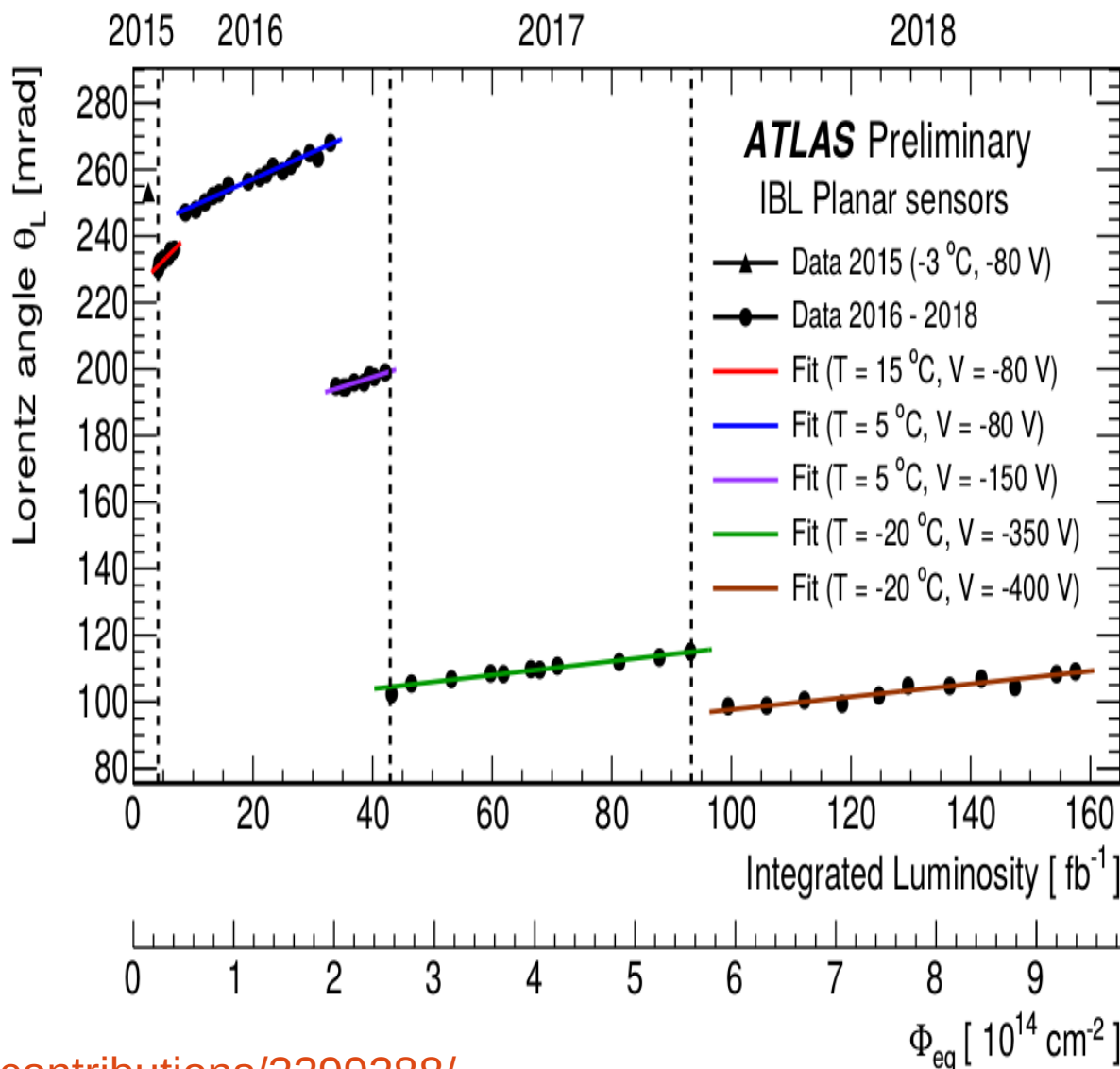
→ Lorentz angle change

Defined as track incidence angle on the module that minimises the pixel multiplicity in cluster!

Clear trend in luminosity!

Detailed discussion in Javier's talk (later):

<https://indico.cern.ch/event/769192/contributions/3299288/>



Fluence and longitudinal position



Module along the pipe axis get different radiation fluence.

Two balancing effects going towards detector edges:

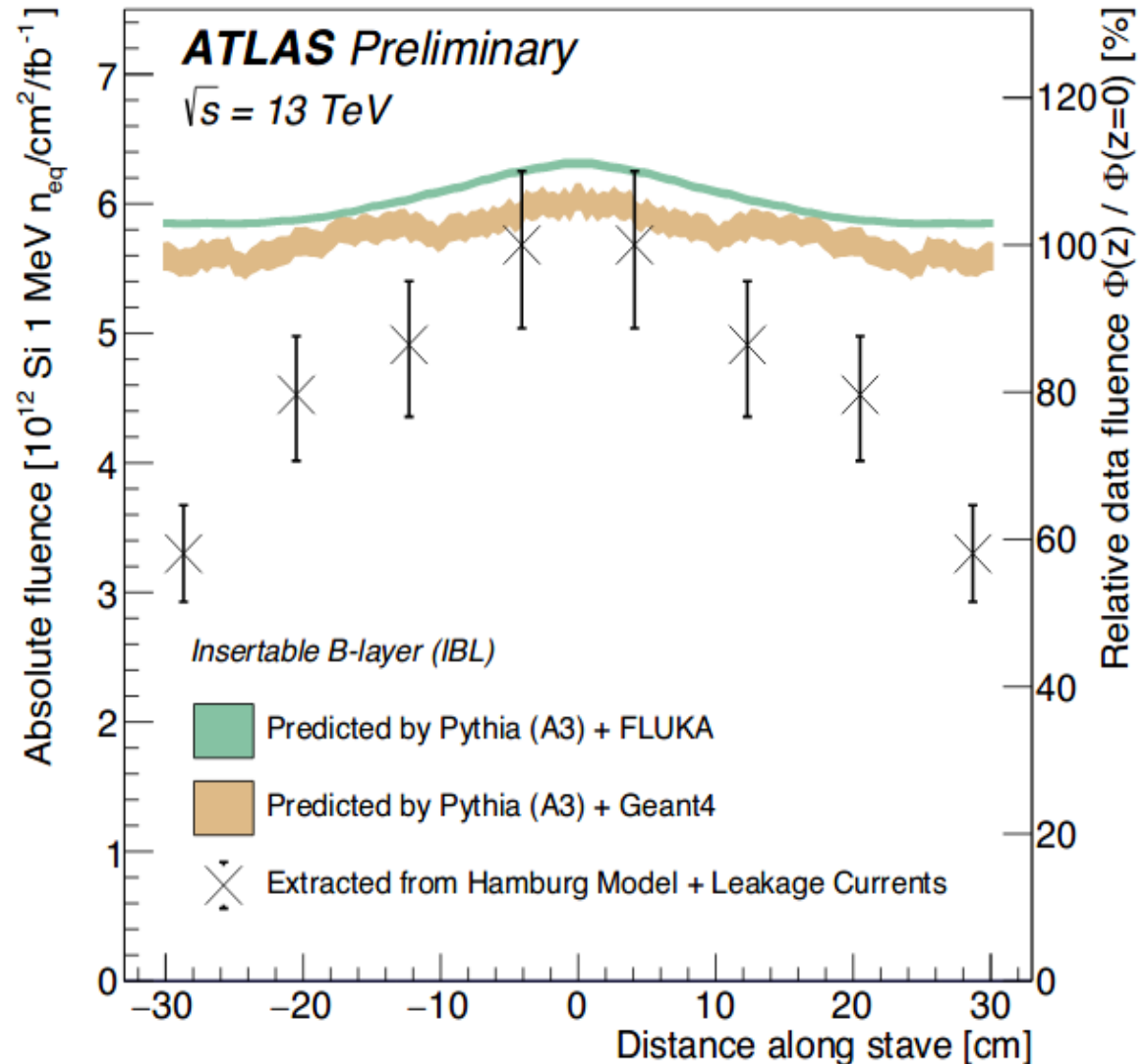
- Elastic pp XS increases
- Covered solid angle decreases

Absorbed fluence **decreases** towards detector edges.

Radiation effects on detector properties investigated wrt the center of the detector

Look at Sven's talk (tomorrow)

<https://indico.cern.ch/event/769192/contributions/3287299/>



Depletion voltage



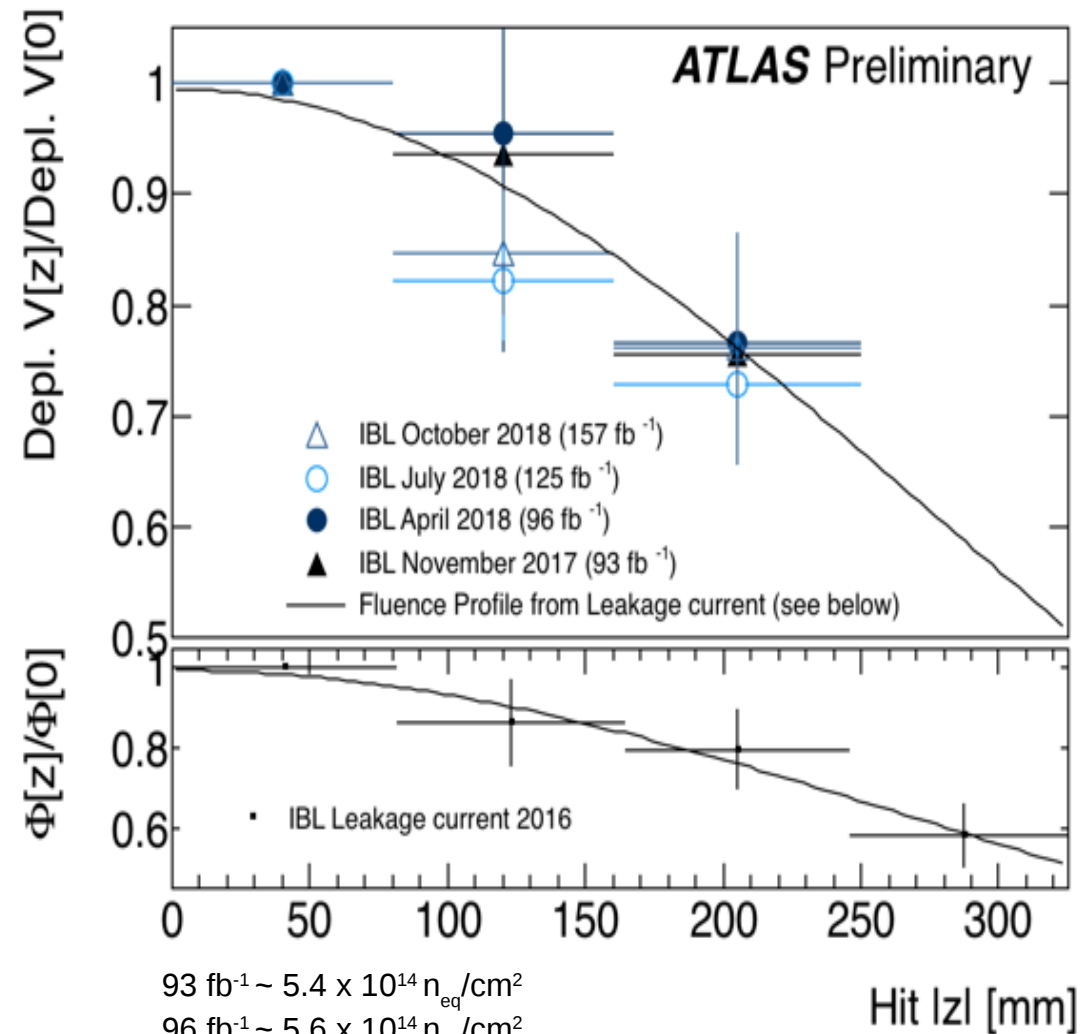
Different prediction from simulations → how to know the relative fluence?

Relative fluence: $\Phi(z)/\Phi(0)$

- Leakage current very sensitive to radiation
- Model = fit on leakage current behaviour vs. z

Relative depletion voltage:

- Same trends for different periods
- Consistent with the expectations from the leakage current



93 $\text{fb}^{-1} \sim 5.4 \times 10^{14} n_{\text{eq}}/\text{cm}^2$
96 $\text{fb}^{-1} \sim 5.6 \times 10^{14} n_{\text{eq}}/\text{cm}^2$
125 $\text{fb}^{-1} \sim 7.6 \times 10^{14} n_{\text{eq}}/\text{cm}^2$
157 $\text{fb}^{-1} \sim 9.2 \times 10^{14} n_{\text{eq}}/\text{cm}^2$

Summary



Properties evolution with fluence

Depletion voltage

- Beam test and collision data comparison at similar absorbed fluences
- Similar results from both observations

Charge Collection Efficiency

- Trends in dE/dx and cluster shapes indicate a loss of charge as expected

Lorentz angle

- Clear evolution with luminosity due to electric field change

Depletion voltage vs. longitudinal position

Different absorbed fluence along the detector

- Clear trend observed
- Consistent with leakage current evolution along the stave

Many thanks for your attention!